AN48840B

Low current consumption, high sensitivity CMOS Hall IC Alternating magnetic field operation (For low-speed rotation detection)

Overview

The AN48840B is a Hall ICs (a magnetic sensor) which has 2 times or more sensitivity and a low current consumption of about one fiftieth compared with our conventional one.

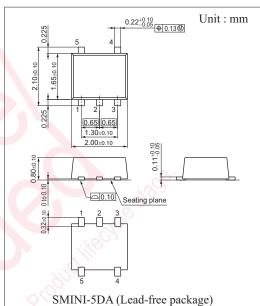
In this Hall IC, a Hall element, a offset cancel circuit, an amplifier circuit, a sample and hold circuit, a Schmidt circuit, and output stage FET are integrated on a single chip housed in a small package by IC technique.

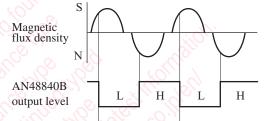
Features

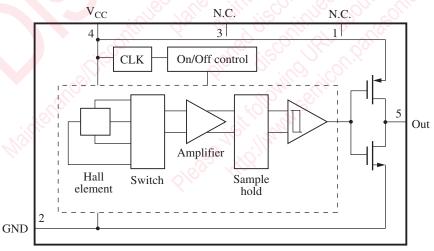
- High sensitivity due to offset cancel circuit and a new sample and hold circuit
- Small current by using intermittent action
- (Average supply current: 56 µA typ., Sampling period: 670 µs typ.)
- Small package (SMD)
- CMOS inverter output (logic output form)

Applications

- Functional operation key, Mouse, Appliances for low-speed rotation detection
- Block Diagram







Pin Descriptions

Pin No.	Symbol	Description	Pin No.	Symbol	Description
1	N.C.	—	4	V _{CC}	Power supply
2	GND	Ground	5	Out	Output
3	N.C.				

Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	V _{CC}	5	V
Output voltage	V _{OUT}	5	V
Supply current	I _{CC}	5	mA
Output current	I _{OUT}	15	mA
Power dissipation *1, *2	P _D	60	mW
Operating ambient temperature *1	T _{opr}	-25 to +75	°C
Storage temperature *1	T _{stg}	-55 to +125	°C

Note) *1: Except for the power dissipation, operating ambient temperature and storage temperature, all ratings are for $T_a = 25^{\circ}C$.

*2: $T_a = 75^{\circ}C$. For the independent IC without a heat sink. Please use within the range of power dissipation, referring to $P_D - T_a$ curve.

Recommended Operating Range

Parameter	Symbol	Range	Unit
Supply voltage	V _{CC}	2.5 to 3.5	V

Electrical Characteristics $T_a = 25^{\circ}C \pm 2^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Operating magnetic flux density 1 *1	B _{HL}	$V_{\rm CC} = 3 V, V_{\rm CC} = 2.5 V$	0.5		6	mT
Operating magnetic flux density 2 *2	B _{LH}	$V_{\rm CC} = 3 V, V_{\rm CC} = 2.5 V$	-6		- 0.5	mT
Output voltage 1	V _{OL1}	$V_{\rm CC} = 3 \text{ V}, I_{\rm O} = 2 \text{ mA}, \text{B} = 6.0 \text{ mT}$		0.1	0.3	V
Output voltage 1	V _{OL2}	$V_{\rm CC} = 2.5 \text{ V}, I_{\rm O} = 2 \text{ mA}, B = 6.0 \text{ mT}$	_	0.1	0.3	V
Output voltage 2	V _{OH1}	$V_{\rm CC} = 3 \text{ V}, I_{\rm O} = -2 \text{ mA}, \text{B} = -6.0 \text{ mT}$	2.7	2.9	<u> </u>	V
Output voltage 2	V _{OH2}	$V_{\rm CC} = 2.5 \text{ V}, I_{\rm O} = -2 \text{ mA}, \text{ B} = -6.0 \text{ mT}$	2.7	2.9	S <u>P</u>	V
Supply current 1 *3	I _{CCAVE}	$V_{\rm CC} = 3 V$	2 - c	56.0	85.0	μΑ
Supply current 2 *3	I _{CC2AVE}	$V_{\rm CC} = 2.5 \rm V$	X Dr.	48.0	72.0	μΑ
Intermittent action time	Tsam	$V_{\rm CC} = 3 V$	490	670	850	μS
Intermittent action time 2	Tsam2	$V_{\rm CC} = 2.5 \rm V$	513	710	890	μS

Note) *1: Symbol B_{H-LS} , B_{H-LN} stands for the operating magnetic flux density where its output level varies from high to low. *2:Symbol B_{L-HS} , B_{L-HN} stands for the operating magnetic flux density where its output level varies from low to high.

*3: $I_{CC_{AVE}} = \{I_{CC_{ON}} \times t_{ON} + I_{CC_{OFF}} \times t_{OFF}\}/\{t_{ON} + t_{OFF}\}$

Design reference data

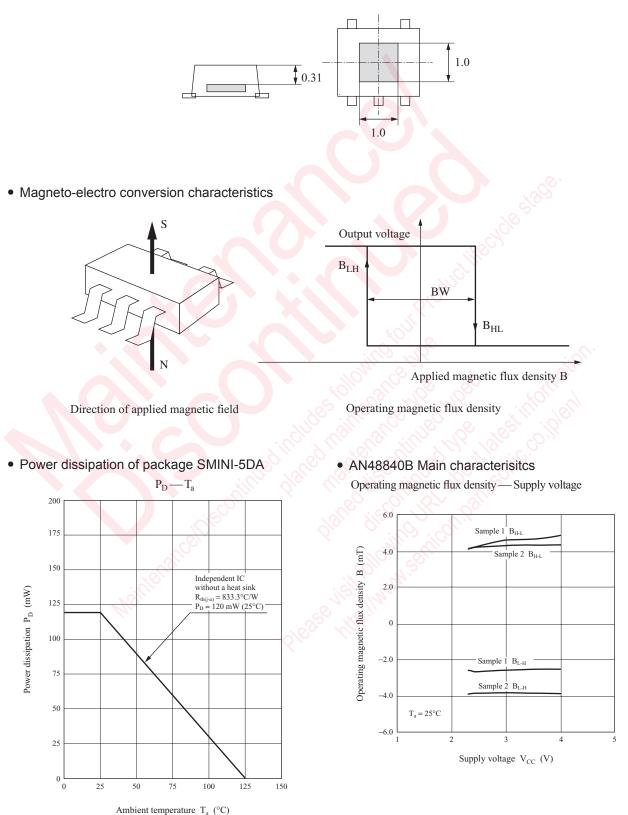
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Hysteresis width	BW	$V_{\rm CC} = 3 V$		7	_	mT
Supply current 3	I _{CCON}	$V_{\rm CC} = 3$ V		1.4	2.1	mA
Supply current 4	I _{CCOFF}	$V_{\rm CC} = 3 V$		2.5	_	μΑ
Supply current 5	I _{CC2ON}	$V_{\rm CC} = 2.5 \rm V$		1.12	1.68	mA
Supply current 6	I _{CC2OFF}	$V_{\rm CC} = 2.5 \rm V$		2.2	_	μΑ
Operating time	t _{ON}	$T_a = -25^{\circ}C$ to 75°C, $V_{CC} = 3$ V	10	26	42	μS
Stop time	t _{OFF}	$T_a = -25^{\circ}C$ to 75°C, $V_{CC} = 3$ V	258	644	1 030	μS
Operating time 2	t _{2ON}	$T_a = -25^{\circ}C$ to 75°C, $V_{CC} = 2.5$ V	11	27	43	μS
Stop time 2	t _{2OFF}	$T_a = -25^{\circ}C$ to 75°C, $V_{CC} = 2.5$ V	270	674	1 078	μS

Note) It will operate normally in approximately 0.67 ms after power on.

Technical Data

• Position of a Hall element (unit in mm)

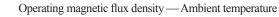
Distance from a package surface to sensor part: 0.31 mm (reference value) A Hall element is placed on the shaded part in the figure.

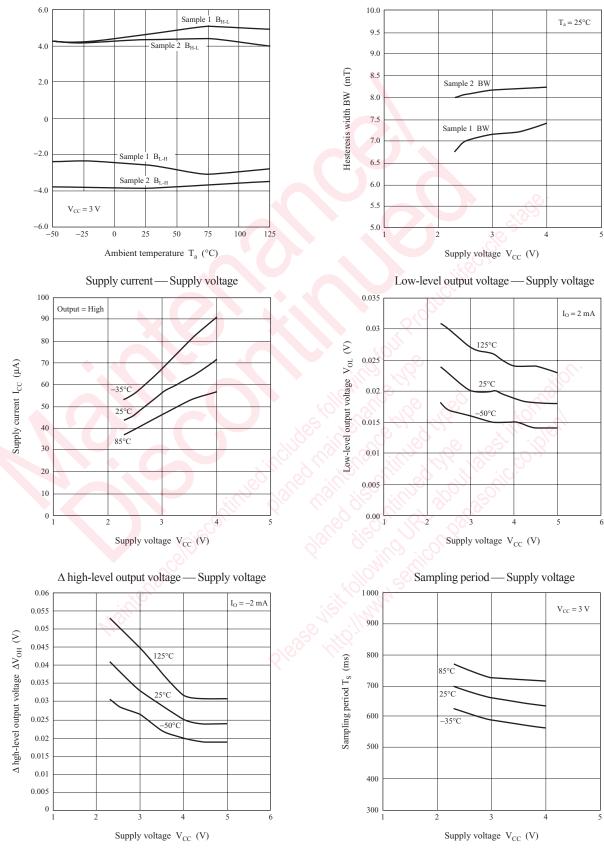


Hysteresis width --- Supply voltage

Technical Data (continued)

AN48840B Main characterisitcs (continued)





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